



# Environment-dependent edge reconstruction of transition metal dichalcogenides: a global search

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## ABSTRACT

The properties of an edge of a transition metal dichalcogenide (TMDC) sensitively depend on its atomic structure; therefore, knowing the exact structure is a precondition for predicting the applications of TMDC, such as in catalysis. Although some edge reconstructions of TMDCs have been reported in previous studies, a global search of TMDC edge structures and calculations of their stabilities are still absent. Here, we propose an approach to explore all possible edge reconstructions of a monolayer TMDC by employing the particle swarm optimization algorithm and first-principles calculations. Taking the most studied TMDC material, MoS<sub>2</sub>, as a representative, we have built a database of the edge structures of TMDCs. Including the five experimentally observed edges, the thirty-four most stable edges with various sulfur concentrations are predicted for the first time. The most stable edge structures of 1H–MoS<sub>2</sub> in different environments along both the armchair and zigzag directions have been predicted and agree well with experimental observations. A specific edge of 1H–MoS<sub>2</sub> in the database can be stabilized by modulating the chemical composition of the atoms, which offers an efficient way to tune the properties of TMDC nanostructures, such as TMDC quantum dots and/or nanoribbons.

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## 1. Introduction

The family of transition metal dichalcogenide (TMDC) two-dimensional (2D) materials has experienced impressive advancements in the past 10 years because of their exotic chemical and physical properties and many potential applications [1–5]. Different from graphene and hexagonal boron nitride (hBN), TMDCs exhibit a combination of an atomically thin crystal structure, a direct and tunable small bandgap, high catalytic activity, and robust flexible mechanical properties, which enable many applications for which graphene and hBN cannot be used. Because of the mature technology of its synthesis, high stability, and robust electronic properties, molybdenum disulfide (MoS<sub>2</sub>) is the most explored TMDC material [6,7]. For example, MoS<sub>2</sub> is one of the most efficient catalysts for the hydrogen evolution reaction (HER) and hydrodesulfurization of sulfur-rich hydrocarbon fuels [8]. In sharp contrast to the noble metal Pt, MoS<sub>2</sub> is an efficient, inexpensive, and earth-abundant electrocatalyst [9–13]. Unlike graphene, the

excellent thermodynamic stability and direct bandgap of 1H–MoS<sub>2</sub> result in much higher potential for applications than the other phases of MoS<sub>2</sub> (1T phase and several derivatives of the 1T phase). Notably, the edge structures of 1H–MoS<sub>2</sub> heavily affect the physical and chemical properties of 2D 1H–MoS<sub>2</sub> and its derivatives, such as nanoribbons, nanotubes, and quantum dots [14–16]. Previous experiments indicated that the HER activity of MoS<sub>2</sub> arises mainly from active edges instead of unmodified basal planes [7]. Although the basal plane of 1H–MoS<sub>2</sub> with vacancies is also active for the HER [17], the edges of 1H–MoS<sub>2</sub> have obvious advantages in catalyzing the HER [18,19]. To improve the catalytic activity of 1H–MoS<sub>2</sub> edges, strategies such as cutting MoS<sub>2</sub> into nanostructures have been employed [6,20–27]. Although these strategies were proven efficient, the lack of an unambiguous understanding of the edge structures of 1H–MoS<sub>2</sub> is a major challenge for further improving the catalytic activity of 1H–MoS<sub>2</sub>.

Experimentally, the Mo-rich edge structures of 1H–MoS<sub>2</sub> were often observed, mostly under high vacuum, by using high-resolution transmission electron microscopy. Some of these edges are bare Mo edges [28–31], and others are sulfur-passivated [11,30,32]. The Mo-rich edges of 1H–MoS<sub>2</sub> were identified as the

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active sites of catalysis [6–8,22]. As of now, the mechanisms for forming various Mo-rich edges of 1H–MoS<sub>2</sub> are still not clear.

In addition to the catalytic activity, the stability of the edges of 1H–MoS<sub>2</sub> can be used to determine the shapes of the most stable nanostructures of 1H–MoS<sub>2</sub> via Wulff construction. Experimentally, the observed shape of the 1H–MoS<sub>2</sub> flake varies from hexagon to triangle via intermediate truncated or multi-apex triangles with changing experimental conditions [33–35]. Although various edge structures of 1H–MoS<sub>2</sub> have been reported, they are mostly pristine edges or slightly modified edges obtained by adding or removing a certain number of S or Mo atoms [36–38]. A pristine edge of 1H–MoS<sub>2</sub>, which can be generated by directly cutting 1H–MoS<sub>2</sub> along a specific direction, always has many unpaired electrons or dangling bonds and is therefore mostly energetically unstable and may undergo edge reconstruction to passivate these dangling bonds [39]. Therefore, uncovering the likely edge reconstruction of 1H–MoS<sub>2</sub> and exploring the edge reconstruction-induced exotic physical or chemical properties are crucial. Moreover, as a two element composite, the chemical environment or chemical composition of the edge could also dramatically change the edge structure. Therefore, how the edge configuration of 1H–MoS<sub>2</sub> evolves with the chemical environment is also unknown.

Here, we develop an approach to predict the edge reconstruction of monolayer TMDCs based on the particle swarm optimization algorithm (PSO) and first-principles calculations. A database of edge structures of TMDCs is built, and taking MoS<sub>2</sub> as a representative, we systematically investigate the edge reconstructions of 1H–MoS<sub>2</sub> under various chemical environments. Our calculations show that the edge of monolayer 1H–MoS<sub>2</sub> can be heavily reconstructed into many possible atomic structures and that the pristine edges are mostly less stable. Thirty-nine highly stable edges of 1H–MoS<sub>2</sub> with various sulfur concentrations are predicted in our calculations, and this study provides excellent explanations for previous experimental observations. Furthermore, the electronic properties of 1H–MoS<sub>2</sub> nanoribbons and nanoflakes are studied.

## 2. Methods

The calculations are performed within the density functional theory framework, carried out within the Vienna ab initio simulation package [40,41] using the projector augmented wave method [42]. The S 3s<sup>2</sup>3p<sup>4</sup> electrons and Mo 4d<sup>5</sup>5s<sup>1</sup> electrons are treated as valence electrons. For all calculations, the Perdew–Burke–Ernzerhof generalized gradient approximation exchange and correlation functional is used [40,43]. Convergence tests give a kinetic energy cutoff of 350 eV, with a grid of spacing of  $2\pi \times 0.03 \text{ \AA}^{-1}$  for the electronic Brillouin zone integration in all phases. The geometries are regarded as optimized when the remanent Hellmann–Feynman forces on the ions are less than 0.01 eV/Å. We choose the energy of a single atom of bulk sulfur as the chemical potential zero point.

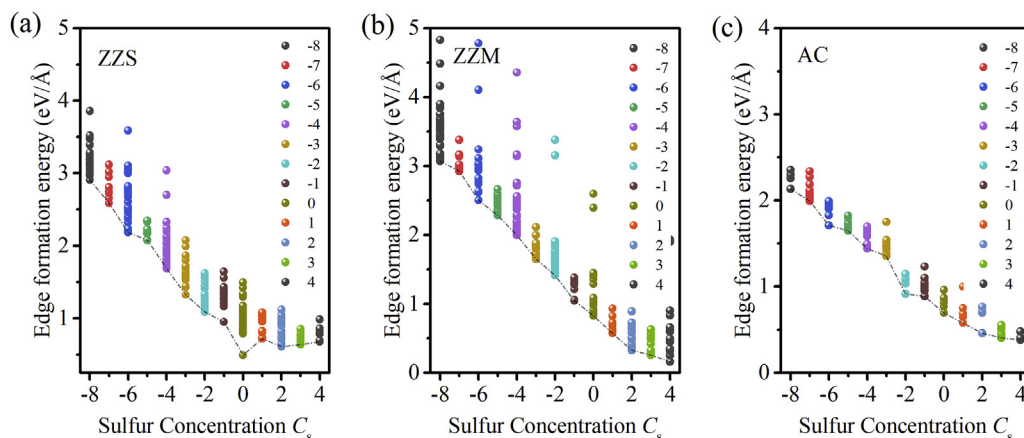
## 3. Results and discussion

Owing to the inherent lack of inversion symmetry and unique sandwich-like atom stacking modes of 1H–MoS<sub>2</sub>, the edges of 1H–MoS<sub>2</sub> have more complex possibilities than those of highly symmetrized graphene and 2D h-BN [44–47]. Mimicking the edge configurations of 1H–MoS<sub>2</sub> is much more difficult compared with those of graphene and 2D h-BN. Here, we develop an approach to predict the edge structures of 2D materials based on PSO, which has excellent performance in exploring the potential energy surface of a material. The basic framework of edge structure prediction is based on the CALYPSO code [48,49], which has been confirmed to be very efficient in the structure prediction field [50,51]. We use frozen nanoribbon models as initial configurations and perform structure

prediction for the edge part of the frozen nanoribbon models (Figs. S1–2). The detailed computational methods can be found in the Supporting Information. We use 1–2 unit cells to perform the edge structure prediction. An extensive structure search of the 1H–MoS<sub>2</sub> edges is performed. Various chemical stoichiometries (Mo<sub>x</sub>S<sub>y</sub>,  $x = 1\text{--}4$  and  $y = 1\text{--}4$  for the single cell;  $x = 1\text{--}6$  and  $y = 1\text{--}6$  for the double cell) at an edge are considered to fully explore the potential energy surface of the edge configuration space of 1H–MoS<sub>2</sub>. For each composition, approximately 1,500 candidate structures are calculated in our global search of the 1H–MoS<sub>2</sub> edges (Fig. S3). In experiments, the concentrations of sulfur and molybdenum atoms are controlled by the precursors, which are usually evaporated sulfur powders and MoO<sub>3</sub> [34]. To simplify calculations, the binary parameter of the chemical composition is converted into a single sulfur concentration ( $C_s = y - 2x$ ). Therefore, the structural stabilities of the candidate edges with various compositions can be evaluated together under a single parameter (sulfur concentration).

To fully understand the edge reconstruction of 1H–MoS<sub>2</sub>, the edge formation energy (Fig. S4) as a function of sulfur concentration is plotted in the form of a convex hull diagram. The convex hull diagram is a widely used criterion for judging the thermodynamic stability of materials. Here, we use it to find the most stable edges at various sulfur concentrations. For the Mo-terminated zigzag edge (ZMZ), S-terminated zigzag edge (ZZS), and armchair edge (AC) edges (Fig. S2), the variation trends of the edge formation energy curves at  $\mu_s = 0 \text{ eV}$  are very similar, as shown in Fig. 1(a–c). As the sulfur chemical composition increases, the edge formation energy generally decreases. The edge formation energy vs. sulfur concentration diagram of the ZMZ edge has a larger descent rate than those of the ZZS and AC edges (Fig. 1(b)), indicating that ZMZ edges have a better ability to reach the energy balance with increasing sulfur chemical composition. Interestingly, with increasing sulfur concentration, the variation trend of the edge formation energies exhibits an obvious odd-even effect, especially for the ZZS and AC edges (Fig. 1(a) and (c)). This can be easily understood because an edge with an even number of sulfur atoms can easily balance the dangling bonds, thus decreasing the edge formation energy. Similar odd-even effects have been observed in the formation of sulfur dimer vacancies [52] and magnetic properties of MoS<sub>2</sub> [53]. The structural evolution with changing sulfur concentration (Fig. 2) also confirms this odd-even effect. For sulfur-rich situations, the sulfur atoms tend to form S<sub>2</sub>-dimer-like units at an edge of 1H–MoS<sub>2</sub>. Moreover, when  $\mu_s$  is 0 eV, the most stable ZMZ and AC edges are obviously located at  $C_s = 4$ , indicating that the ZMZ and AC edges with sufficient sulfur concentrations are stable in sulfur-rich situations. However, for the ZZS edge, even if more sulfur atoms or metal atoms are added, the pristine sulfur-terminated zigzag edge is still the most stable edge at  $\mu_s = 0 \text{ eV}$ . This result is in good agreement with experimental observations that the pristine sulfur-terminated zigzag edge is the most observed sulfur-terminated zigzag edge [33].

The most stable edge structures of the ZZS, ZMZ, and AC edges at various sulfur concentrations are selected to construct the first database of 1H–MoS<sub>2</sub>, as shown in Fig. 2 (Figs. S5 and S6). In addition to the five experimentally observed edges, 34 edges of 1H–MoS<sub>2</sub> are predicted for the first time. In perfect 1H–MoS<sub>2</sub>, one Mo atom bonds with six S atoms, and one S atom bonds with three Mo atoms, forming a highly stable honeycomb lattice. However, in a nanoribbon or other finite nanostructure of MoS<sub>2</sub>, the Mo atoms and S atoms at an edge no longer have perfect triangular prismatic coordination and triangular pyramidal coordination, respectively. Therefore, the pristine edges of 1H–MoS<sub>2</sub> usually have very high potential for reconstruction because of the presence of dangling bonds induced by excess unpaired electrons. These excess unpaired

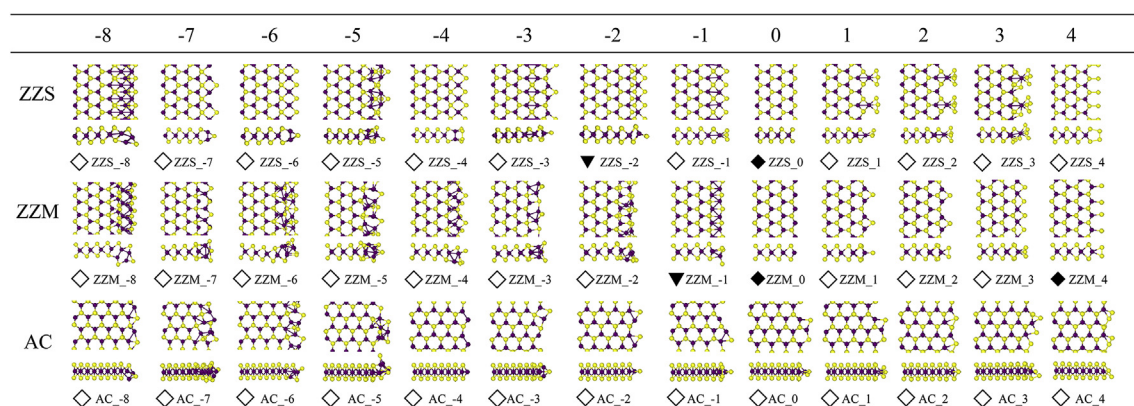


**Fig. 1.** Edge formation energies of the (a) S-terminated zigzag edge (ZZS), (b) Mo-terminated zigzag edge (ZMZ), and (c) armchair edge (AC) as a function of sulfur concentration  $C_s$  at the chemical potential of sulfur  $\mu_s = 0$  eV. The energy of bulk sulfur is selected as the zero point of the chemical potential.

electrons redistribute to ensure the energy balance of the system. When the sulfur concentration is 0, the pristine ZZS and ZMZ edges are the most stable edges. However, the pristine AC edge undergoes a reconstruction to the AC<sub>0</sub> edge. Overall, the pristine ZMZ, ZZS, and AC edges of 1H-MoS<sub>2</sub> tend to be covered by additional sulfur or metal atoms. The numbers of additional sulfur or metal atoms are determined by the sulfur composition. A common feature of edge reconstruction under sulfur-rich conditions is the occurrence of sulfur atom dimerization. S<sub>2</sub>-dimer-like units frequently appear at the three types of 1H-MoS<sub>2</sub> edges, especially for the ZMZ and ZZS edges. For the pristine ZZS edge, the coordination number of sulfur atoms at an edge is two. These unsaturated sulfur atoms need to bond with other atoms to balance their dangling bonds. When  $C_s$  is in the range of 0–4, the unsaturated sulfur atoms bind with S<sub>2</sub>-dimer units or a mixture of metal atoms and S<sub>2</sub>-dimer units. When  $C_s$  is in the range of –8 to 0, a combination of metal atoms and sulfur monomers instead of S<sub>2</sub>-dimer units balances the dangling bonds of unsaturated sulfur atoms. For the pristine ZMZ edge, the metal atoms at the edge have redundant electrons. The redundant electrons of metal atoms at the edge will redistribute. When  $C_s$  is 4, two pairs of S<sub>2</sub>-dimer-like units bond with metal atoms at the edge. These two pairs of S<sub>2</sub>-dimer units are parallel to each other. As  $C_s$  decreases, the two pairs of S<sub>2</sub>-dimer units transform into a mixture of a S<sub>2</sub>-dimer unit and sulfur monomers and finally into sulfur monomers. When the metal-rich situation is reached, metal atoms at an edge are covered by a combination of metal and sulfur atoms.

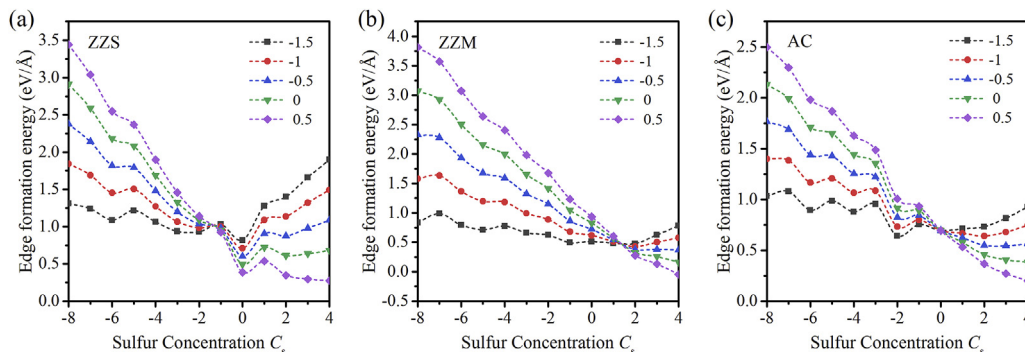
For the pristine AC edge, S<sub>2</sub>-dimer units and sulfur monomers appear at the edge when  $C_s$  is in the range of 2–4. When  $C_s$  is less than 2, a combination of metal and sulfur atoms covers the pristine AC edge. In our calculations, the metal-rich edges with ‘Mo dimer’ units are not energetically favorable with respect to the sulfur-terminated metal-rich edges. Therefore, the experimentally observed bare ‘Mo dimer’ edge is a sulfur-terminated edge because the sulfur atoms are usually not easy to distinguish in the scanning transmission electron microscopy (STEM) images, or the sulfur atoms are knocked out by electron irradiation.

The chemical potential is another important factor for the stability of edge structures in addition to the thermodynamic stability. To simultaneously investigate the effect of the chemical potential and chemical composition on the 1H-MoS<sub>2</sub> edge, we plot the edge formation energy vs. chemical potential and chemical composition curves in Fig. 3(a–c). According to previous theoretical and experimental studies [37,38], the chemical potential of sulfur is chosen in the range of –1.5 eV–0.5 eV, which is relative to the energy of bulk sulfur. Both sulfur-rich and metal-rich situations are considered in our calculation. With changing chemical potential of sulfur, the variation trends of the edge formation energies for the ZZS, ZMZ, and AC edges are very similar. Several local minima are observed in the edge formation energy curves, especially for the ZZS and AC edges. However, the intersection points of the edge formation energies for the ZZS, ZMZ, and AC edges under various chemical potentials are different because of the intrinsic



**Fig. 2.** Top and side views of the most stable edge structures of the ZZS, ZMZ, and AC edges at various sulfur concentrations. The  $\diamond$ ,  $\nabla$  and  $\blacklozenge$  shapes indicate the edges found in the current work only, in previous experiments, and in previous theoretical and experimental works, respectively. ZZS, S-terminated zigzag edge; ZMZ, Mo-terminated zigzag edge; AC, armchair edge.





**Fig. 3.** Variation in the edge formation energy of 1H-MoS<sub>2</sub> as a function of chemical potential and chemical composition. ZZS, S-terminated zigzag edge; ZMZ, Mo-terminated zigzag edge; AC, armchair edge.

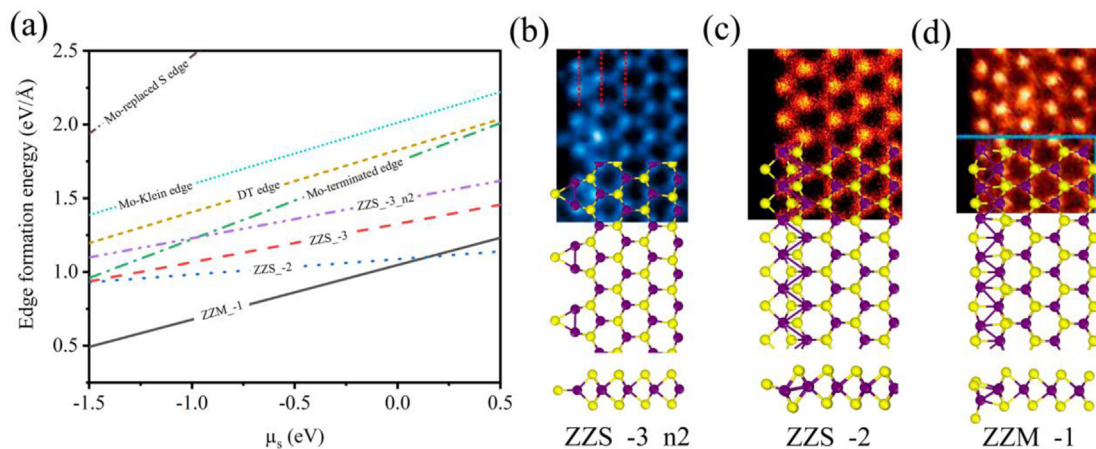
differences in the chemical bonding environment of the initial pristine edges. For ZZS edges, the intersection point of edge formation energies is close to the value of  $-1$  because the initial pristine ZZS edge is a metal-deficient edge (Fig. 3(a)). The sulfur atom bonds at the edge of the initial pristine zigzag edge are unsaturated. These atoms need to bond with metal atoms to balance the dangling bonds. In contrast to ZZS edges, the initial pristine ZMZ edge is a sulfur-deficient edge. The intersection point of edge formation energies is close to the value of  $1$  for ZMZ edges because the metal atoms at the edge need sulfur atoms to balance their dangling bonds (Fig. 3(b)). For AC edges, the intersection point of edge formation energies is located at zero because the initial pristine AC edge is not affected by the chemical potential (Fig. 3(c)). Interestingly, the odd-even effect of edge formation energies is enhanced by a decrease in the chemical potential of sulfur, especially for AC edges.

For ZZS edges (Fig. 3(a)), under an extremely high chemical potential of sulfur, the most stable edge structure is located at  $C_s = 4$ . As the chemical potential of sulfur decreases, a small energy barrier at  $C_s = 1$  is crossed at  $\mu_s = 0$  eV. The ZZS<sub>0</sub> edge gradually becomes the most stable edge structure when  $\mu_s$  is in the range of  $0$  to  $-1.5$  eV. The pristine ZZS edge (ZZS<sub>0</sub>) is very special because it is almost the most stable edge over the whole range of chemical potential  $\mu_s$ . Under the metal-rich situation, two local minima occur when  $C_s$  is in the range of  $-2$  to  $-6$  (ZZS<sub>-2</sub> edge and ZZS<sub>-6</sub> edge). However, the edge formation energies of the ZZS<sub>-2</sub> edge and ZZS<sub>-6</sub> edge are still higher than that of the initial ZZS<sub>0</sub> edge. In total, four local minima occur over the whole range of  $\mu_s$ . The energy differences between the ZZS<sub>0</sub> edge and ZZS<sub>-2</sub>/ZZS<sub>-3</sub> edge decrease with decreasing  $\mu_s$ . At  $\mu_s = -1.5$  eV, the energy difference between the ZZS<sub>0</sub> edge and the ZZS<sub>-2</sub>/ZZS<sub>-3</sub> edge is approximately  $0.12$  eV/Å, which can be easily overcome at high temperatures. The metastable ZZS<sub>-2</sub> edge and ZZS<sub>-3</sub> edge are expected to appear in experiments. Similar edge structures have been observed in experiments, which were denoted the DT edge and Mo-Klein edge (Fig. S7). We calculated the edge formation energies of our proposed and experimentally observed edges as shown in Fig. 4(a) and compared the structural features of them with the experimental observations (Fig. 4(b–d)). The ZZS<sub>-2</sub> edge can explain the STEM results of experiments [29]. The calculated edge formation energies indicate that the ZZS<sub>-2</sub> edge is more stable than the DT edge (Fig. 4(a)). Furthermore, the ZZS<sub>-2</sub> edge can also be used to explain Chen's experimental observations. The ZZS<sub>-2</sub> edge has a great advantage in energy compared with the Mo-replaced S edge. We also find that the metastable ZZS<sub>-3</sub>n<sub>2</sub> edge (Fig. S5) in our database can explain the experimental STEM results very well (Fig. 4(b)). Although the ZZS<sub>-3</sub>n<sub>2</sub> edge is the second most stable phase at  $C_s = -3$ , the edge formation energy of the ZZS<sub>-3</sub>n<sub>2</sub> edge

is much lower than that of the previously proposed Mo-Klein edge. Another local minimum edge, ZZS<sub>-6</sub>, is expected to be stable at a lower  $\mu_s$ .

For ZMZ edges (Fig. 3(b)), the most stable structure is the ZMZ<sub>4</sub> edge under high  $\mu_s$ . This result is in good agreement with the previous study. The ZMZ<sub>4</sub> edge is seen as the most stable structure in most studies [8,39,54]. As  $\mu_s$  decreases, a very small energy difference at  $C_s = 3$  is crossed. Then, the ZMZ<sub>2</sub> edge becomes the most stable edge. According to Fig. 2, the outermost Mo atoms of the ZMZ<sub>2</sub> edge and ZMZ<sub>4</sub> edge are terminated by S<sub>2</sub>-dimer-like units. At  $\mu_s = -0.5$  eV, the energy difference between the ZMZ<sub>3</sub> edge and ZMZ<sub>2</sub>/ZMZ<sub>4</sub> edge is very small, indicating that they have almost equal chances of appearing in experiments. The ZMZ<sub>3</sub> edge is alternately composed of S<sub>2</sub>-dimer-like units and S monomers. At  $\mu_s = -1.5$  eV, the energy differences among the ZMZ<sub>2</sub>, ZMZ<sub>1</sub>, ZMZ<sub>0</sub>, and ZMZ<sub>-1</sub> edges are very small, indicating that they also have almost equal chances of appearing in experiments. The metal-rich ZMZ<sub>-1</sub> edge has already been observed in recent experiments (Fig. 4(d)) [30,31]. Comparing edge formation energies (Fig. 4(a)), the ZMZ<sub>-1</sub> edge is energetically more favorable than the candidate structure proposed by Zhou et al. [30,31]. Furthermore, we found that Mo atoms at an edge are passivated by sulfur atoms even if the metal-rich situation is reached. The edges with bare Mo atoms do not have an advantage in energy. The reason for the experimentally observed bare Mo edges should be that the electron irradiation knocks out the outermost sulfur atoms in experiments. Although the highly stable edges such as ZMZ<sub>-1</sub>, ZZS<sub>-2</sub>, and ZZS<sub>-3</sub>n<sub>2</sub> are not observed in experiments, they are very important for the deep understanding of edge reconstruction of TMDCs.

For AC edges (Fig. 3(c)), under extremely high chemical potential  $\mu_s$ , the most stable edge structure is the sulfur-rich AC<sub>4</sub> edge. As  $\mu_s$  decreases, the AC<sub>4</sub>, AC<sub>3</sub>, and AC<sub>2</sub> edges gradually become the most stable edges. When  $\mu_s$  is extremely low ( $\mu_s = -1.5$  eV), a small energy difference at  $C_s = -1$  is overcome, and then, the AC<sub>-2</sub> edge becomes the most stable edge. The AC<sub>-2</sub> edge is also the global minimum of the potential energy surface at  $\mu_s = -1.5$  eV. For the metal-rich situation ( $C_s = -8 \sim -2$ ), as  $\mu_s$  decreases, the odd-even effect of the edge formation energies of AC edges becomes more obvious. The edge formation energies exhibit an interesting periodic oscillation with changing  $C_s$ . However, the AC<sub>-2</sub> edge is still the global minimum, which is not affected by the odd-even effect-induced energy oscillation. Furthermore, under low  $\mu_s$ , the energy difference between the most stable AC<sub>-2</sub> edge and the second most stable AC<sub>-4</sub> edge is approximately  $0.24$  eV/Å, indicating that a transition from the AC<sub>-2</sub> edge to the metal-rich edges (AC<sub>-8</sub>, AC<sub>-7</sub>, AC<sub>-6</sub>, AC<sub>-5</sub>, AC<sub>-4</sub>, and AC<sub>-3</sub> edges) is very difficult even if more metal atoms are added. For the high  $\mu_s$  situation, the energy difference between the most stable AC<sub>-2</sub> edge and sulfur-rich

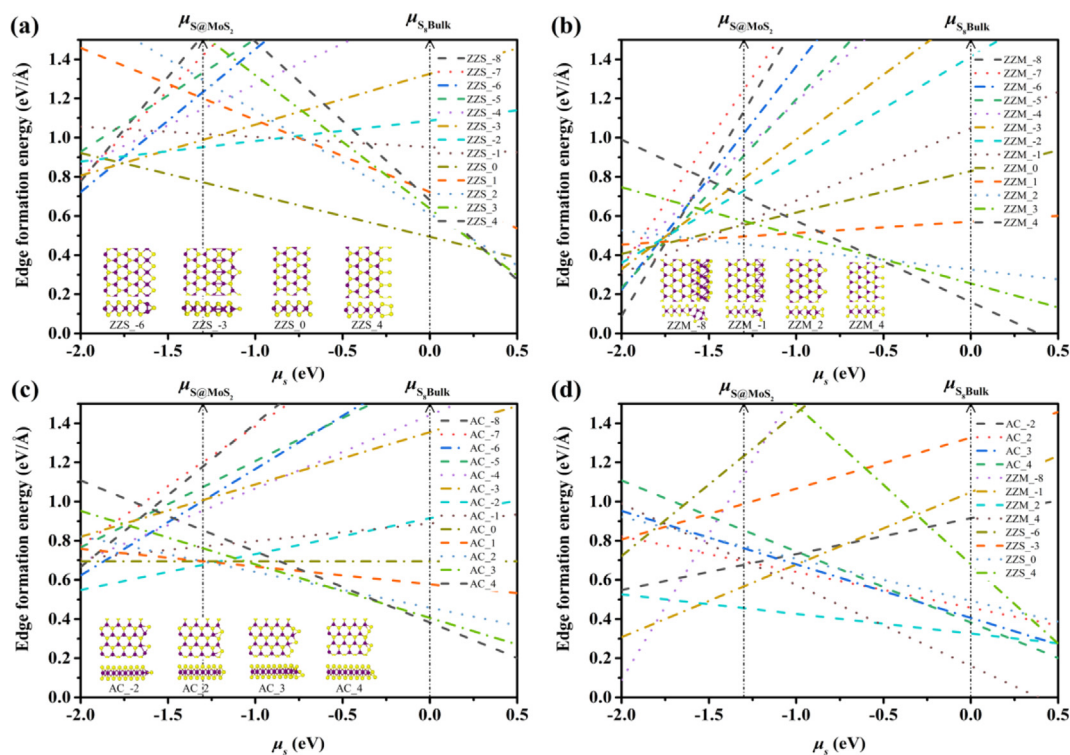


**Fig. 4.** (a) Edge formation energy as a function of chemical potential for selected edges. Comparison of experimental STEM observations and theoretical results of (b) ZZZS\_-3\_n2, (c) ZZZS\_-2, and (d) ZZZM\_-1 edges. Reprinted (adapted) with permission from ref. 29 and ref. 30 Copyright 2013 and 2018 American Chemical Society. ZZZS, S-terminated zigzag edge; ZZZM, Mo-terminated zigzag edge.

edges (AC\_-1, AC\_0, AC\_1, and AC\_2 edges) is less than 0.1 eV/Å, and the edge formation energies of the AC\_-1, AC\_0, AC\_1, and AC\_2 edges are almost equal, suggesting that these sulfur-rich edges (AC\_-1, AC\_0, AC\_1, and AC\_2 edges) have equal possibilities of appearing in experiments.

We also investigated the relationship between the edge formation energies and the chemical potential of the ZZZM, ZZZS, and AC edges (Fig. 5). For ZZZS edges (Fig. 5(a)), the ZZZS\_4 edge is the most stable edge when  $\mu_s$  is in the range of 0.3–0.5 eV. ZZZS\_0 becomes the most stable when  $\mu_s$  is less than 0.3 eV. As  $\mu_s$  decreases, the ZZZS\_-3 edge and ZZZS\_-6 edge become more stable at  $\mu_s$  of -1.75 eV and -1.82 eV, respectively. For ZZZM edges (Fig. 5(b)), the ZZZM\_4

edge and ZZZM\_2 edge are the two most stable edges when  $\mu_s$  is greater than -1.53 eV. The ZZZM\_4 edge transforms into the ZZZM\_2 edge at  $\mu_s = -0.52$  eV. When  $\mu_s$  is less than -1.53 eV, the ZZZM\_-1 edge and ZZZM\_-8 edge become more stable. The ZZZM\_-1 edge transforms into the ZZZM\_-8 edge at  $\mu_s = -1.80$  eV. For AC edges (Fig. 5(c)), as  $\mu_s$  decreases, the transition sequence is the AC\_4, AC\_3, AC\_2, and AC\_-2 edges. Overall, the reconstructed ZZZM edges are always the most stable (Fig. 5(d)). For a high  $\mu_s$  situation, the edge formation energy differences between ZZZM edges and ZZZS edges is greater than 0.4 eV/Å. As  $\mu_s$  decreases, the energy difference between ZZZM edges and ZZZS edges decreases and becomes close to 0.2 eV/Å when  $\mu_s$  is approximately -0.52 eV. Then, the



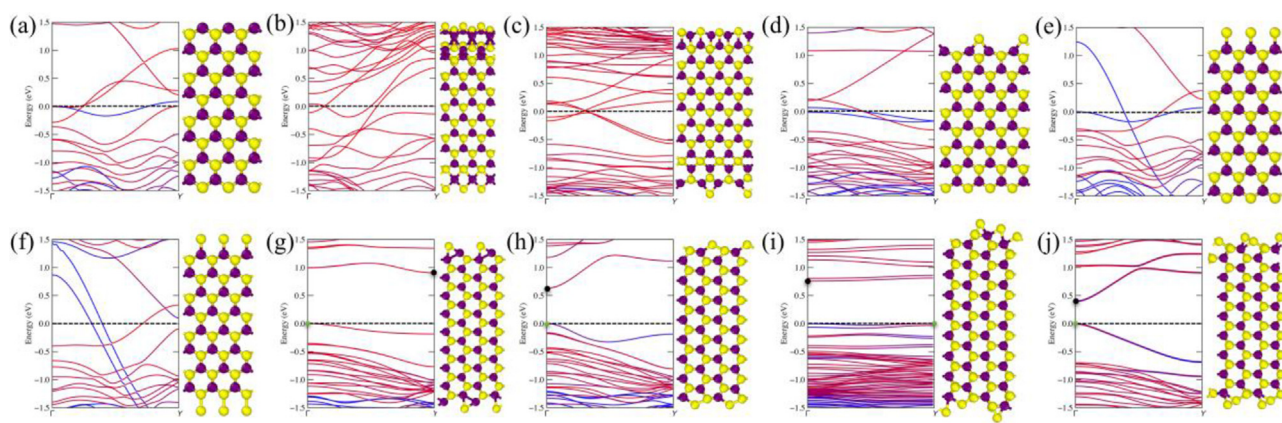
**Fig. 5.** Edge formation energies at various sulfur concentrations as a function of chemical potential  $\mu_s$  for the (a) ZZZS edge, (b) ZZZM edge, and (c) AC edge. (d) Edge formation energies of the most stable edges of the ZZZS, ZZZM, and AC edges as a function of chemical potential  $\mu_s$ . The structures of the most stable ZZZS, ZZZM, and AC edges are shown in the inset. ZZZS, S-terminated zigzag edge; ZZZM, Mo-terminated zigzag edge; AC, armchair edge.

energy difference between ZZM and ZZS edges increases again. The variation trend of the energy difference between ZZS and AC edges is similar to that between ZZM and ZZS edges. The energy difference between ZZS and AC edges is greater than 0.12 eV/Å under a high chemical potential of sulfur. As  $\mu_s$  decreases, the energy difference between ZZS and AC edges becomes small. When  $\mu_s$  is in the range of  $-1.265$  eV to  $-0.05$  eV, the energy difference remains at approximately 0.1 eV/Å. When  $\mu_s$  is less than  $-1.26$  eV, the energy difference between ZZS and AC edges increases again. At  $\mu_s = -1.74$  eV, the energy difference between ZZS and AC edges is close to 0.26 eV/Å. As  $\mu_s$  decreases, the energy difference between ZZS and AC edges decreases again. At  $\mu_s = -2$  eV, the energy difference between ZZS and AC edges is approximately 0.18 eV/Å. The energy range of AC edges is located in the middle of the energies of ZZM and ZZS edges. AC edges will appear at a lower chemical potential of sulfur. Based on crystal growth theory, the edges with the lowest edge formation energy will be easily retained, and the edges with higher edge formation energies will disappear during growth. Therefore, the ZZM\_4 edge can be easily obtained under high  $\mu_s$ . The ZZM\_2 edge can be obtained under low  $\mu_s$ . At extremely low  $\mu_s$ , the ZZM\_1 edge and ZZM\_8 edge will appear in experiments. The pristine ZZM edge is not stable because the dangling bonds of metal atoms need to be passivated.

Next, we study the electronic band structures of highly stable 1H-MoS<sub>2</sub> nanoribbons composed of the most stable edge structures at various chemical potentials (Fig. 6). Based on the analysis of the thermodynamic stabilities of 1H-MoS<sub>2</sub> edges (Fig. 5(d)), five highly stable zigzag nanoribbons (ZZ-NR-1, ZZ-NR-2, ZZ-NR-3, ZZ-NR-4, and ZZ-NR-5) and four highly stable armchair nanoribbons (AC-NR-1, AC-NR-2, AC-NR-3, and AC-NR-4) are constructed. A zigzag nanoribbon (ZZ-NR-0) composed of pristine ZZS and ZZM edges is considered as a reference. Our calculations indicate that ZZ-NR-0 is metallic (Fig. 6(a)). Both the S<sub>p</sub> and Mo<sub>d</sub> electrons contribute to the metallization of ZZ-NR-0. The five highly stable zigzag nanoribbons of 1H-MoS<sub>2</sub> are all metallic (Fig. 6(b–f)). This result is in good agreement with a previous study that reported that the zigzag edges of typical 2D semiconducting materials exhibit metallic properties [29]. However, the contributions of the S<sub>p</sub> and Mo<sub>d</sub> electrons to the metallization of the five highly stable zigzag nanoribbons of 1H-MoS<sub>2</sub> greatly differ with changing chemical potential of sulfur. A previous study confirmed that the electronic

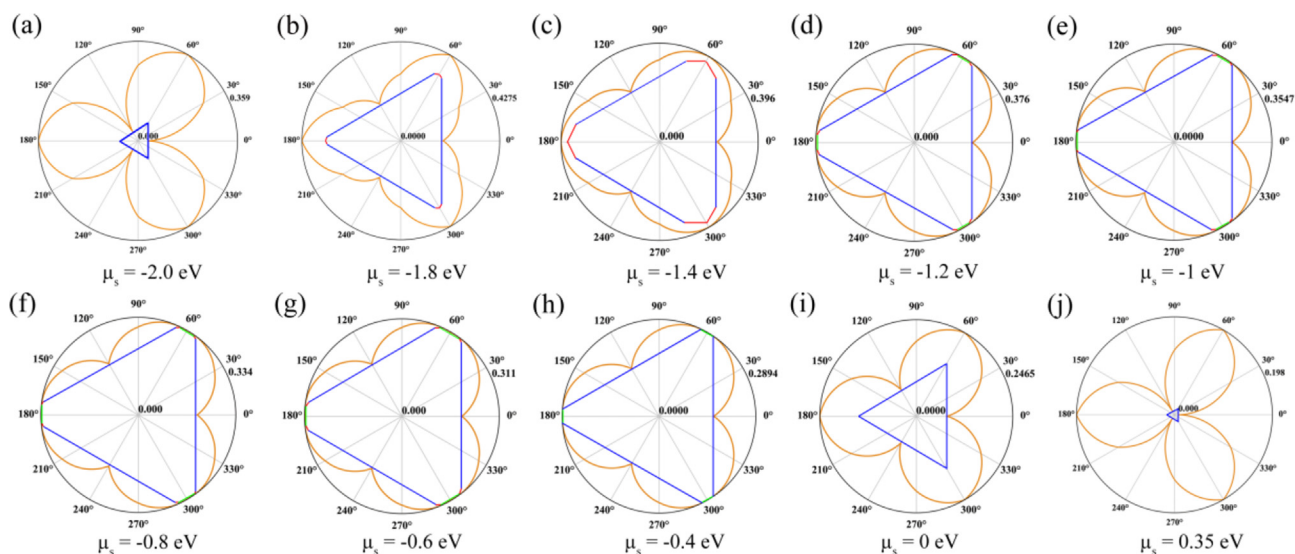
bands around the Fermi level in 2D TMDCs are mainly dominated by the edge atoms [55]. According to the projected band structures, under high  $\mu_s$ , the metallic properties of zigzag nanoribbons are determined by both the *p* orbital of S atoms and *d* orbital of Mo atoms (Fig. 6(d–f)). Under low  $\mu_s$ , the metallic properties are determined only by the *d* orbital of Mo atoms (Fig. 6(b and c)). These results provide a strategy to tune the catalytic activity of the edges of 1H-MoS<sub>2</sub> by changing the chemical potential of sulfur. Moreover, the four highly stable armchair nanoribbons of 1H-MoS<sub>2</sub> (AC-NR-1, AC-NR-2, AC-NR-3, and AC-NR-4) are semiconductors with obviously tunable bandgaps in the range of 0.4–1 eV (Fig. 6(g–j)). The obvious difference in the electronic properties between the zigzag and armchair nanoribbons of 1H-MoS<sub>2</sub> indicate that this material has potential applications in the catalysis and electronic device fields.

Fig. 7(a–j) shows the evolution of the equilibrium shape of 1H-MoS<sub>2</sub> nanoflakes with changing chemical potential of sulfur. Under high  $\mu_s$ , the equilibrium shape of the 1H-MoS<sub>2</sub> nanoflake is a triangle with three ZZM\_4 edges (Fig. 7(j)). This triangle can be maintained for  $\mu_s$  in the range of 0.35 to  $-0.4$  eV (Fig. 7(i and j)). As  $\mu_s$  decreases, the vertex of the triangle exhibits some truncation. At  $\mu_s = -0.4$  eV, the triangle transforms into a truncated triangle, which has a mixture of ZZS\_0 edges and arbitrary chiral edges (Fig. 7(h)). As  $\mu_s$  further decreases, the three ZZS\_0 edges of the truncated triangle gradually first expand. When  $\mu_s$  is less than  $-0.6$  eV, the three ZZS\_0 edges of the truncated triangle gradually shrink (Fig. 7(d–g)). At the same time, the AC\_2 edge and AC\_2 edge have an obvious advantage in energy. They expand with decreasing  $\mu_s$ . Finally, the 1H-MoS<sub>2</sub> nanoflake has a nonagonal shape with three ZZM\_2 edges and six AC\_2 edges (Fig. 7(c)). A similar nonagonal shape was predicted in a recent study of monolayer GaSe nanoflakes [55]. When  $\mu_s$  is extremely low, the nonagonal shape gradually reverts to the triangle (Fig. 7(a and b)). The triangular 1H-MoS<sub>2</sub> nanoflake composed of ZZM\_8 edges is the most stable shape at extremely low  $\mu_s$ . Our simulations indicate that the shape of the MoS<sub>2</sub> nanoflake is strongly dependent on the chemical potential of sulfur, which induces the shape of the 1H-MoS<sub>2</sub> nanoflake to transform from a triangle to a truncated triangle and then back to a triangle. This result is in good agreement with previous theoretical calculations [56]. However, there are some differences in the equilibrium shape of 1H-MoS<sub>2</sub> nanoflakes



**Fig. 6.** Projected band structures of some highly stable MoS<sub>2</sub> nanoribbons. (a) A zigzag nanoribbon with pristine ZZM and ZZS edges (ZZ-NR-0), (b) a zigzag nanoribbon with ZZM<sub>8</sub> and ZZS<sub>6</sub> edges (ZZ-NR-1), (c) a zigzag nanoribbon with ZZM<sub>1</sub> and ZZS<sub>3</sub> edges (ZZ-NR-2), (d) a zigzag nanoribbon with ZZM<sub>2</sub> and ZZS<sub>0</sub> edges (ZZ-NR-3), (e) a zigzag nanoribbon with ZZM<sub>4</sub> and ZZS<sub>4</sub> edges (ZZ-NR-4), (f) a zigzag nanoribbon with ZZM<sub>4</sub> and ZZS<sub>4</sub> edges (ZZ-NR-5), (g) an armchair nanoribbon with two AC<sub>2</sub> edges (AC-NR-1), (h) an armchair nanoribbon with two AC<sub>2</sub> edges (AC-NR-2), (i) an armchair nanoribbon with two AC<sub>3</sub> edges (AC-NR-3), and (j) an armchair nanoribbon with two AC<sub>4</sub> edges (AC-NR-4). The blue and red colors indicate the contributions of S<sub>p</sub> and Mo<sub>d</sub> electrons. The horizontal dashed lines denote the position of the Fermi level. The black and green spheres denote the positions of the lowest unoccupied molecular orbital (LUMO) and the highest occupied molecular orbital (HOMO), respectively. ZZS, S-terminated zigzag edge; ZZM, Mo-terminated zigzag edge; AC, armchair edge. (For interpretation of the references to color in this figure legend, the reader is referred to the Web version of this article.)





**Fig. 7.** Polar plots of the formation energies of MoS<sub>2</sub> edges as a function of chiral angle  $\chi$  ( $0^\circ \leq \chi \leq 360^\circ$ ) at various chemical potentials of sulfur  $\mu_s$ , (a)  $-2.0$  eV (Mo-rich), (b)  $-1.8$  eV (c)  $-1.4$  eV, (d)  $-1.2$  eV, (e)  $-1$  eV, (f)  $-0.8$  eV, (g)  $-0.6$  eV, (h)  $-0.4$  eV, (i)  $0$  eV, and (j)  $0.35$  eV (S-rich). The blue, green, and red solid lines denote ZSM, ZZS, and AC edges, respectively. ZZS, S-terminated zigzag edge; ZSM, Mo-terminated zigzag edge; AC, armchair edge. (For interpretation of the references to color in this figure legend, the reader is referred to the Web version of this article.)

between our computational results and experimental observed ones under STEM or in CVD growth [33]. In the current calculation, only the most stable edge structures with global minimum energies are considered to determine the equilibrium shape of monolayer 1H-MoS<sub>2</sub>. The equilibrium shape of monolayer 1H-MoS<sub>2</sub> will change in experiments because other experimental factors, such as the temperature, defects, precursor fluxes, electron irradiation, and substrate, will modulate the edges of 1H-MoS<sub>2</sub> to local minima of the potential energy surface [33,57]. These complex experimental environments also provide an opportunity to capture the meta-stable edge structures such as Mo-Klein edge, DT edge, and Mo-terminated edge (Fig. S7) in experiments. Another possible reason is that, during CVD growth of 1H-MoS<sub>2</sub>, the dominating edge is generally the edge grow slowest, determined by the kinetic Wulff construction [58], whereas in the current study, the thermodynamic Wulff construction only predicts the edges with the lowest formation energy. Therefore, the 1H-MoS<sub>2</sub> nanoflakes constructed by our theoretical method could be different from the experimentally observed ones, either under STEM or in CVD growth.

#### 4. Conclusions

In summary, we have systematically explored the possible edge reconstructions of TMDC materials and presented a database of the edge structures of 1H-MoS<sub>2</sub>. The potential energy surfaces of three types of 1H-MoS<sub>2</sub> edges, ZSM, ZZS, and AC, are fully explored, and the most stable edges are found to vary with the chemical environment or the chemical potential. Our global search finds 34 highly stable edge structures, and their relative stabilities as a function of chemical potential are calculated. The edge structures predicted in the current calculations match the experimental observations very well. The edge evolution of 1H-MoS<sub>2</sub> nanoflakes and the electronic properties of 1H-MoS<sub>2</sub> nanoribbons are explored. Some unique sulfur-terminated edges with S<sub>2</sub> dimers or sulfur monomers have potential applications as catalysts. In addition to the most stable edge structures, several metastable edge structures with small energy differences with respect to the most stable structure are expected to be synthesized experimentally. This database of edge structures of TMDCs provides not only

fundamental information for the study of 1H-MoS<sub>2</sub> edges but also new opportunities in the study of the edge structures of various 2D 1H phase TMDC materials.

#### Data availability

The raw/processed data required to reproduce these findings cannot be shared at this time as the data also forms part of an ongoing study.

#### Authors contribution

**Ding Feng:** Conceptualization, Methodology, Supervision, Writing-Reviewing and Editing. **Li Da:** Methodology, Software, Data curation, Writing-Original draft preparation.

#### Declaration of Competing Interest

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this article.

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#### Appendix A. Supplementary data

Supplementary data to this article can be found online at <https://doi.org/10.1016/j.mtadv.2020.100079>.

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